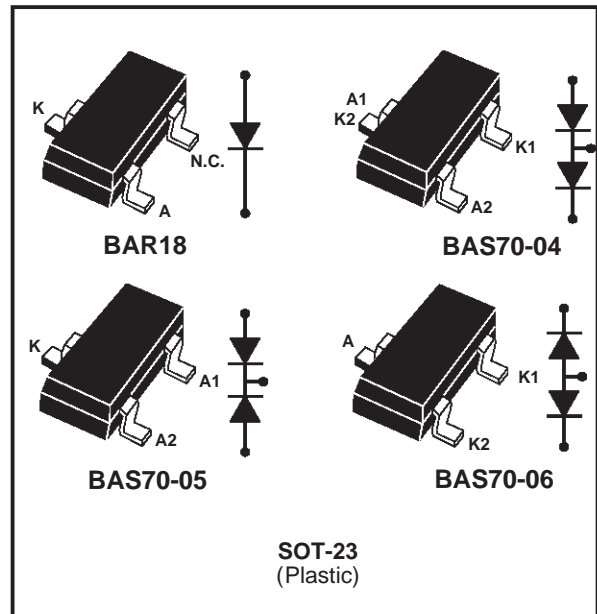


**SMALL SIGNAL SCHOTTKY DIODES**

**DESCRIPTION**

Low turn-on and high breakdown voltage diodes intended for ultrafast switching and UHF detectors in hybrid micro circuits.



**ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	70	V
$I_F$	Continuous forward current	15	mA
$P_{tot}$	Power dissipation (note 1)	$T_{amb} = 25^{\circ}C$ 250	mW
$T_{stg}$	Maximum storage temperature range	- 65 to +150	$^{\circ}C$
$T_j$	Maximum operating junction temperature *	150	$^{\circ}C$
$T_L$	Maximum temperature for soldering during 10s	260	$^{\circ}C$

**Note 1:** for double diodes,  $P_{tot}$  is the total dissipation of both diodes

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

**THERMAL RESISTANCE**

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient (*)	500	$^{\circ}C/W$

(\*) Mounted on epoxy board with recommended pad layout.

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions	Min.	Typ.	Max.	Unit
$V_{BR}$	$T_j = 25^\circ\text{C} I_R = 10\mu\text{A}$	70			V
$V_F^*$	$T_j = 25^\circ\text{C} I_F = 1\text{mA}$			410	mV
$I_R^{**}$	$T_j = 25^\circ\text{C} V_R = 50\text{V}$			200	nA

Pulse test: \*  $t_p = 380\mu\text{s}$ ,  $\delta < 2\%$   
 \*\*  $t_p = 5\text{ms}$ ,  $\delta < 2\%$

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions	Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ\text{C} V_R = 0\text{V}$ F = 1MHz			2	pF
$\tau^*$	$T_j = 25^\circ\text{C} I_F = 5\text{mA}$ Krakauer Method			100	ps

\* Effective carrier life time.

Fig. 1-1: Forward voltage drop versus forward current (low level).

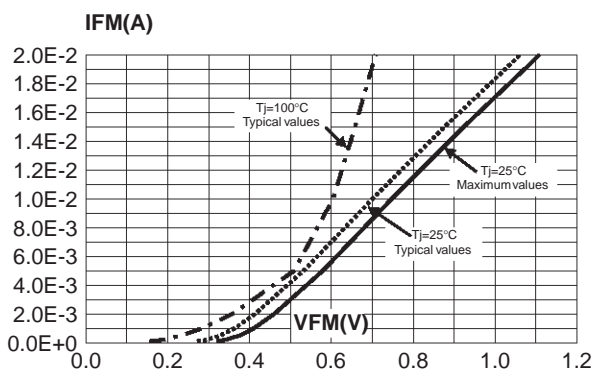


Fig. 1-2: Forward voltage drop versus forward current (high level).

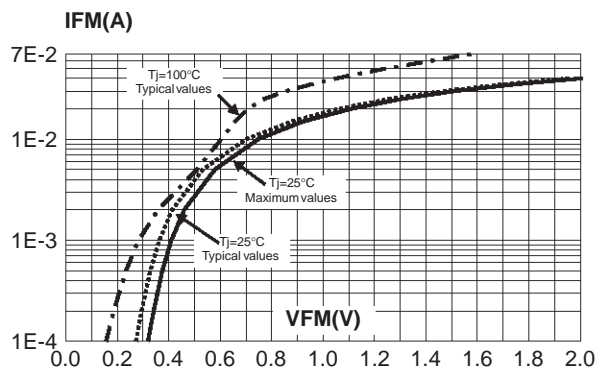


Fig. 2: Reverse leakage current versus reverse voltage applied (typical values).

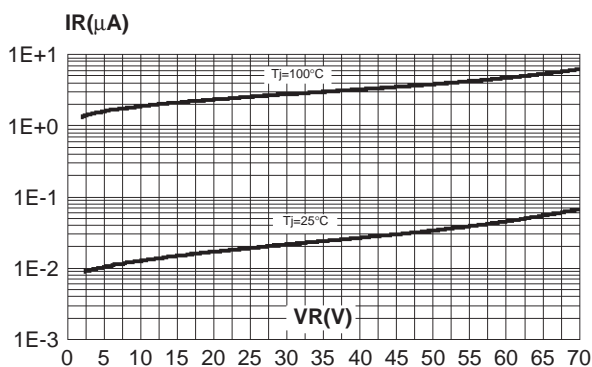
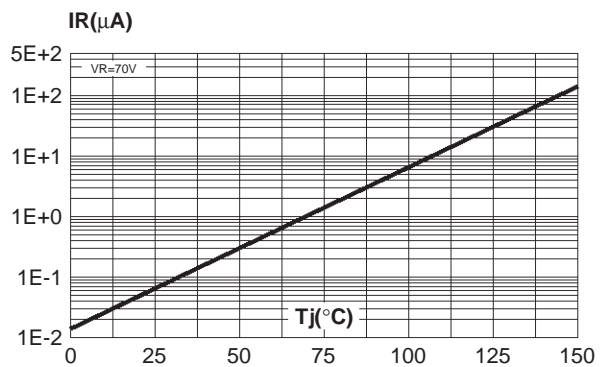
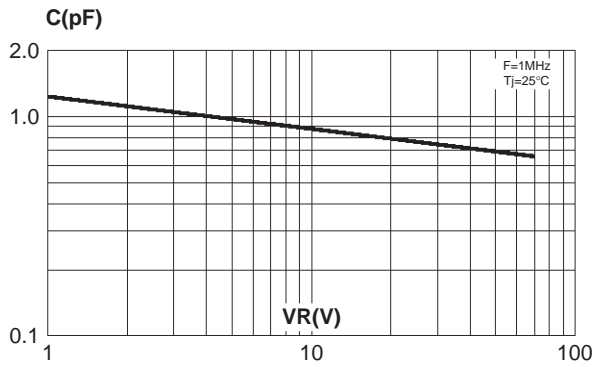


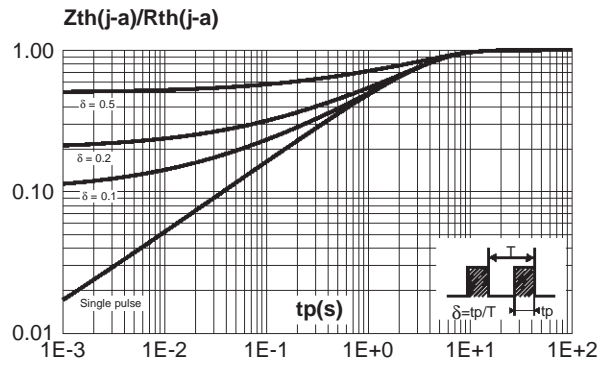
Fig. 3: Reverse leakage current versus junction temperature (typical values).



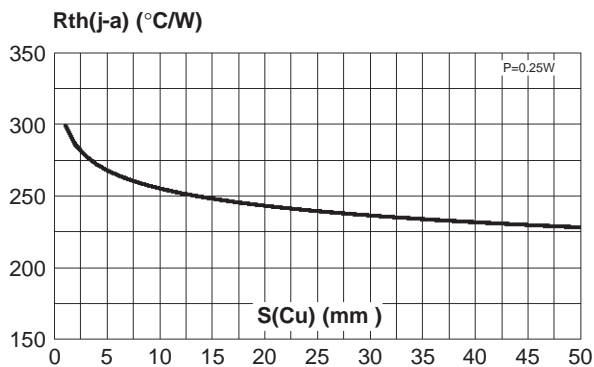
**Fig. 4:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 5:** Relative variation of thermal impedance junction to ambient versus pulse duration (alumine substrate 10mm\*8mm\*0.5mm).

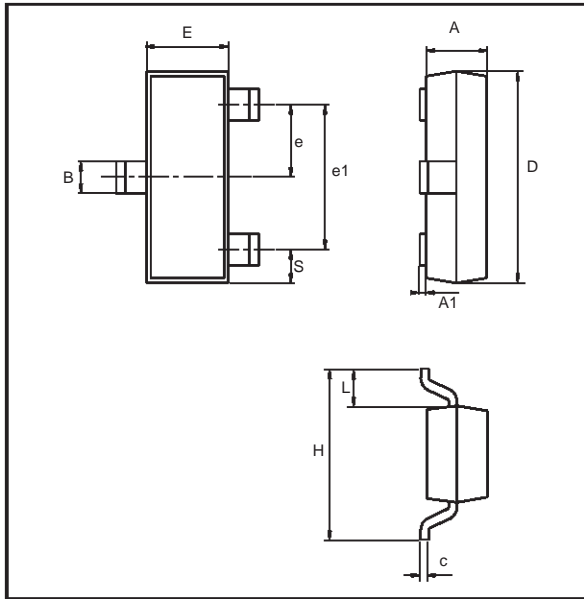


**Fig. 6:** Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: 35μm).



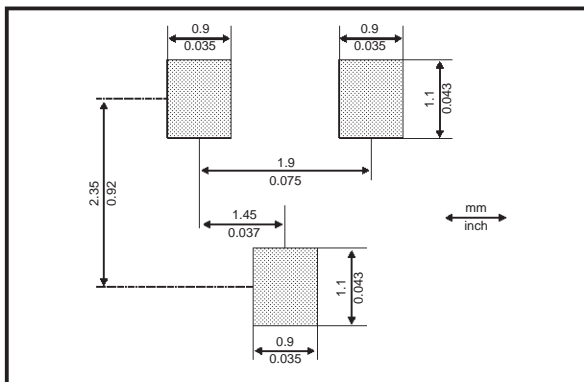
PACKAGE MECHANICAL DATA

SOT 23 (Plastic)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.89	1.4	0.035	0.055
A1	0	0.1	0	0.004
B	0.3	0.51	0.012	0.02
c	0.085	0.18	0.003	0.007
D	2.75	3.04	0.108	0.12
e	0.85	1.05	0.033	0.041
e1	1.7	2.1	0.067	0.083
E	1.2	1.6	0.047	0.063
H	2.1	2.75	0.083	0.108
L	0.6 typ.		0.024 typ.	
S	0.35	0.65	0.014	0.026

FOOT PRINT DIMENSIONS



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR18	D76	SOT-23	0.01g	3000	Tape & reel
BAS70-04	D96	SOT-23	0.01g	3000	Tape & reel
BAS70-05	D97	SOT-23	0.01g	3000	Tape & reel
BAS70-06	D98	SOT-23	0.01g	3000	Tape & reel

Epoxy meets UL94,V0

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